NSN 5962-01-450-6525

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:

1.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

F-15s

Features Provided:

Electrostatic sensitive and programmed and ultraviolet erasable and burn in

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Input Circuit Pattern:

15 input

Criticality Code Justification:

Cbbl

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, digital-programmable read only memory, uv erasable

Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

250.00 nanoseconds access

Memory Device Type:

Pal

Special Features:

Altered item make from smd 8202505ya; generic pn 27128 and 27128a and 27c128

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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